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2SC4110 — NPN Triple Diffused Planar Silicon Transistor 400V/25A Switching Regulator Applications

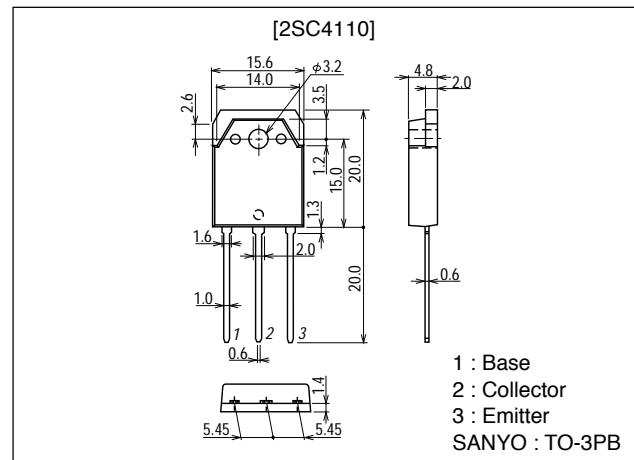
Features

- High breakdown voltage and high reliability.
- Fast switching speed.
- Wide ASO.
- Adoption of MBIT process.

Package Dimensions

unit:mm

2022A



Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		500	V
Collector-to-Emitter Voltage	V_{CEO}		400	V
Emitter-to-Base Voltage	V_{EBO}		7	V
Collector Current	I_C		25	A
Collector Current (Pulse)	I_{CP}	$PW \leq 300\mu\text{s}$, duty cycle $\leq 10\%$	40	A
Base Current	I_B		8	A
Collector Dissipation	P_C		2.5	W
		$T_c = 25^\circ\text{C}$	160	W
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = 400\text{V}$, $I_E = 0$			10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 5\text{V}$, $I_C = 0$			10	μA

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2SC4110

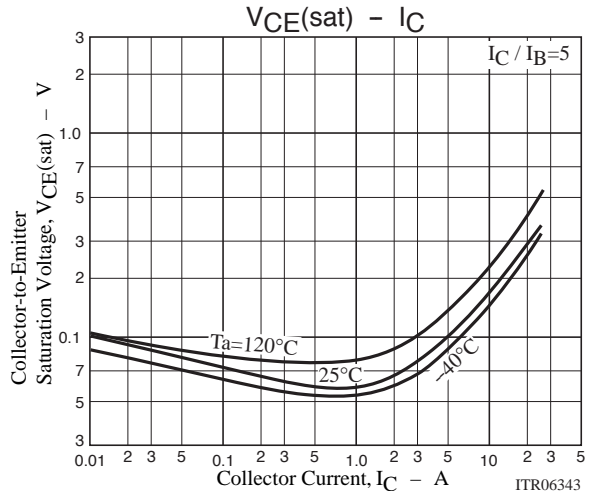
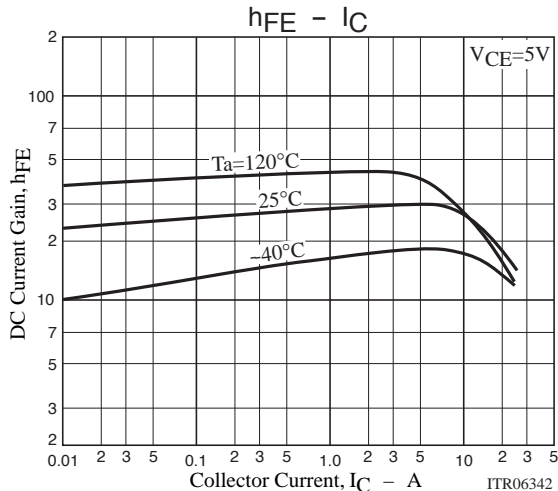
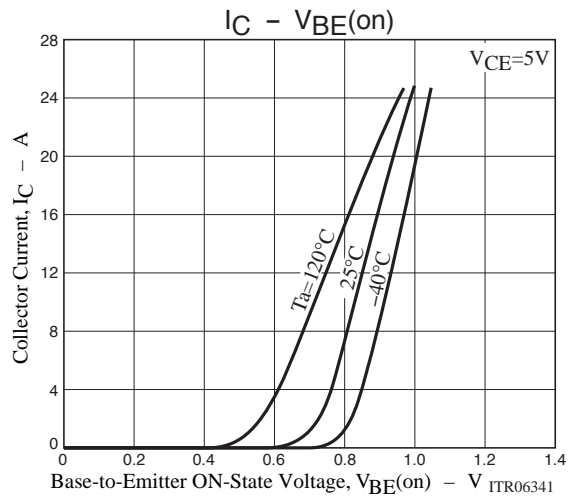
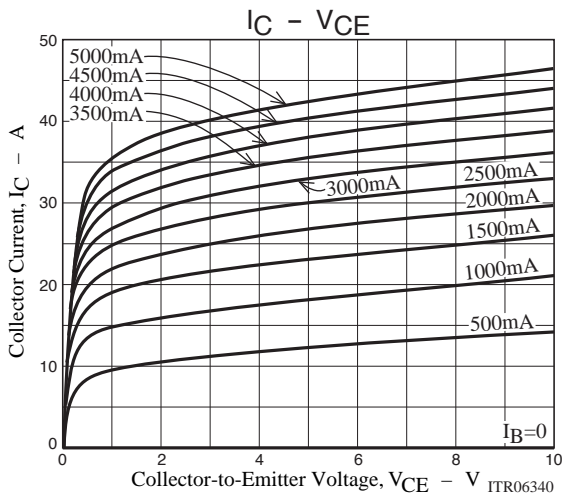
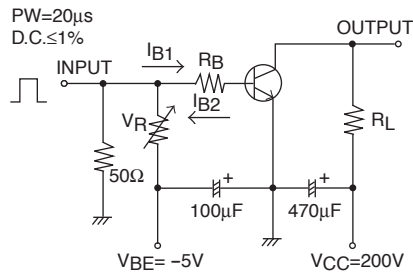
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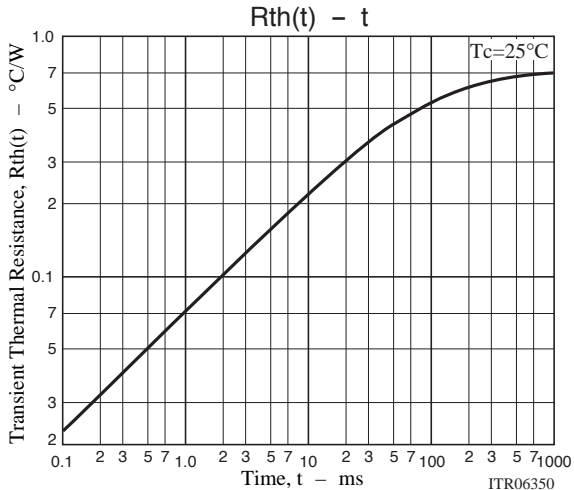
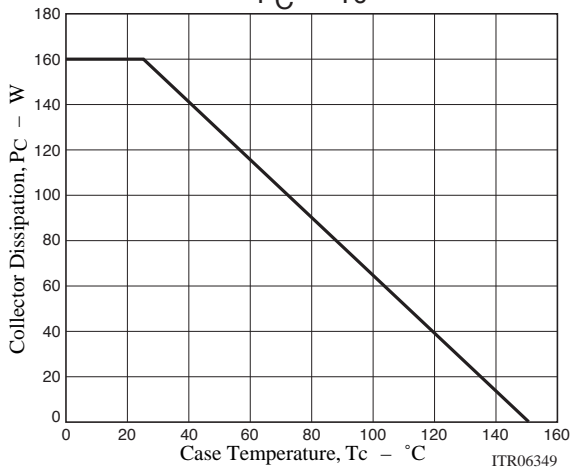
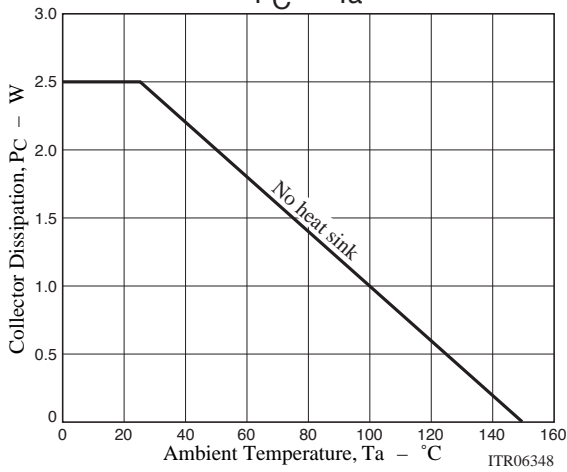
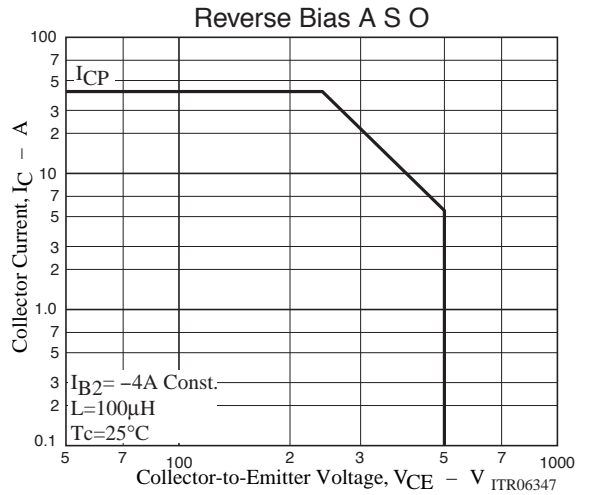
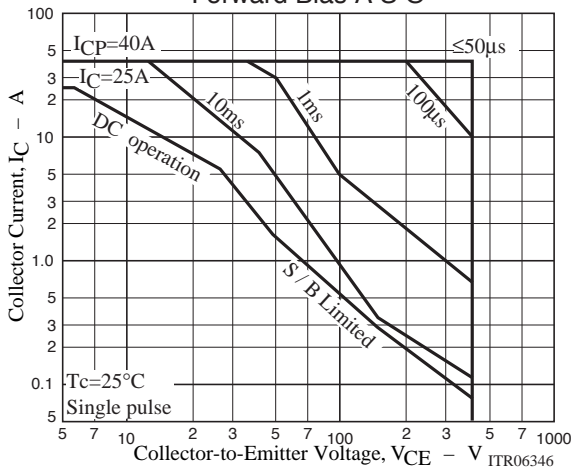
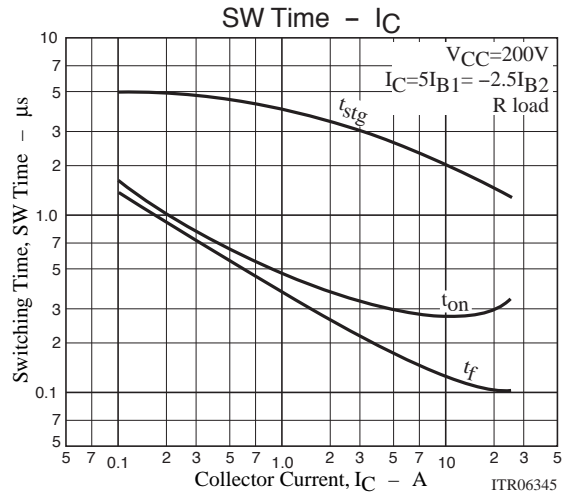
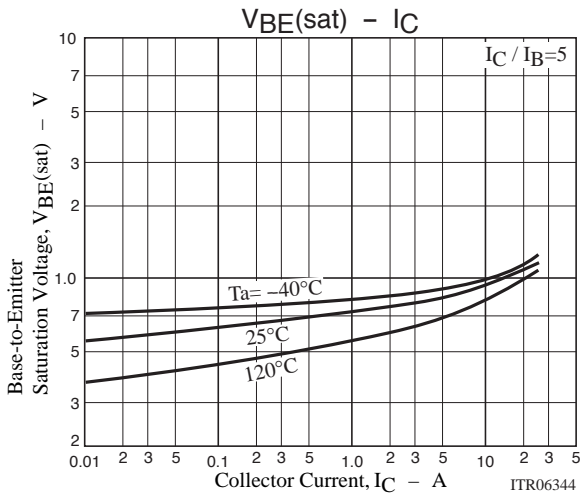
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
DC Current Gain	h_{FE1}	$V_{CE}=5V, I_C=3.2A$	15*		50*	
	h_{FE2}	$V_{CE}=5V, I_C=16A$	10			
	h_{FE3}	$V_{CE}=5V, I_C=10mA$	10			
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=16A, I_B=3.2A$			0.8	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=16A, I_B=3.2A$			1.5	V
Gain-Bandwidth Product	f_T	$V_{CE}=10V, I_C=3.2A$		20		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		300		pF
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=1mA, I_E=0$	500			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=10mA, R_{BE}=\infty$	400			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=1mA, I_C=0$	7			V
Collector-to-Emitter Sustain Voltage	$V_{CEX(sus)}$	$I_C=10A, I_{B1}=1A, I_{B2}=-4A, L=200\mu H, \text{clamped}$	400			V
Turn-ON Time	t_{on}	$I_C=20A, I_{B1}=4A, I_{B2}=-8A, R_L=10\Omega, V_{CC}=200V$			0.5	μs
Storage Time	t_{stg}	$I_C=20A, I_{B1}=4A, I_{B2}=-8A, R_L=10\Omega, V_{CC}=200V$			2.5	μs
Fall Time	t_f	$I_C=20A, I_{B1}=4A, I_{B2}=-8A, R_L=10\Omega, V_{CC}=200V$			0.3	μs

* : The h_{FE1} of the 2SC4110 is classified as follows. When specifying the h_{FE1} rank, specify two ranks or more in principle.

Rank	L	M	N
h_{FE}	15 to 30	20 to 40	30 to 50

Switching Time Test Circuit





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